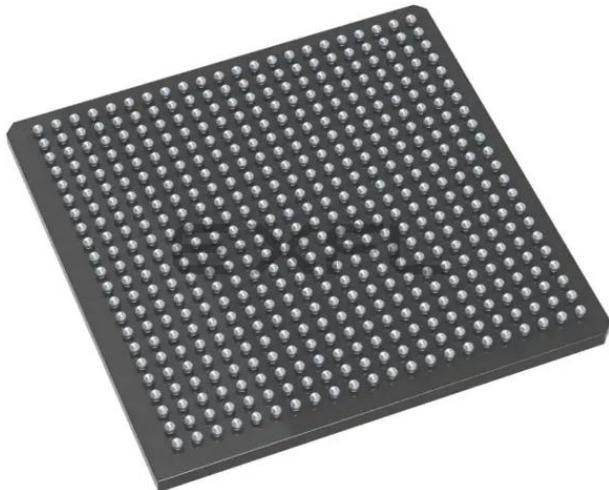


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[**Embedded - System On Chip \(SoC\): The Heart of Modern Embedded Systems**](#)

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are [Embedded - System On Chip \(SoC\)](#)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details

Product Status	Active
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	256KB
RAM Size	64KB
Peripherals	DDR, PCIe, SERDES
Connectivity	CANbus, Ethernet, I²C, SPI, UART/USART, USB
Speed	166MHz
Primary Attributes	FPGA - 50K Logic Modules
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2s050-fg484i

Table 19 • Maximum Data Rate Summary Table for Voltage-Referenced I/O in Worst-Case Industrial Conditions

I/O	MSIO	MSIOD	DDRIO	Unit
LPDDR			400	Mbps
HSTL 1.5 V			400	Mbps
SSTL 2.5 V	510	700	400	Mbps
SSTL 1.8 V			667	Mbps
SSTL 1.5 V			667	Mbps

Table 20 • Maximum Data Rate Summary Table for Differential I/O in Worst-Case Industrial Conditions

I/O	MSIO	MSIOD	Unit
LVPECL (input only)	900		Mbps
LVDS 3.3 V	535		Mbps
LVDS 2.5 V	535	700	Mbps
RSDS	520	700	Mbps
BLVDS	500		Mbps
MLVDS	500		Mbps
Mini-LVDS	520	700	Mbps

Table 21 • Maximum Frequency Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions

I/O	MSIO	MSIOD	DDRIO	Unit
PCI 3.3 V	315			MHz
LVTTL 3.3 V	300			MHz
LVCMOS 3.3 V	300			MHz
LVCMOS 2.5 V	205	210	200	MHz
LVCMOS 1.8 V	147.5	200	200	MHz
LVCMOS 1.5 V	80	110	118	MHz
LVCMOS 1.2 V	60	80	100	MHz
LPDDR– LVCMOS 1.8 V mode			200	MHz

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 3.0\text{ V}$

Table 91 • PCI/PCIX AC Switching Characteristics for Receiver for MSIO I/O Bank (Input Buffers)

On-Die Termination (ODT)	T_{PY}		T_{PYS}			Unit
	-1	-Std	-1	-Std		
None	2.229	2.623	2.238	2.633	ns	

Table 92 • PCI/PCIX AC switching Characteristics for Transmitter for MSIO I/O Bank (Output and Tristate Buffers)

T_{DP}	T_{ZL}	T_{ZH}	T_{HZ}	T_{LZ}		
-1	-Std	-1	-Std	-1	-Std	Unit
2.146	2.525	2.043	2.404	2.084	2.452	6.095
					7.171	5.558
					6.539	ns

2.3.6 Memory Interface and Voltage Referenced I/O Standards

This section describes High-Speed Transceiver Logic (HSTL) memory interface and voltage reference I/O standards.

2.3.6.1 High-Speed Transceiver Logic (HSTL)

The HSTL standard is a general purpose high-speed bus standard sponsored by IBM (EIA/JESD8-6). IGLOO2 FPGA and SmartFusion2 SoC FPGA devices support two classes of the 1.5 V HSTL. These differential versions of the standard require a differential amplifier input buffer and a push-pull output buffer.

Minimum and Maximum DC/AC Input and Output Levels Specification (Applicable to DDRIO Bank Only)

Table 93 • HSTL Recommended DC Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{DDI}	1.425	1.5	1.575	V
Termination voltage	V_{TT}	0.698	0.750	0.803	V
Input reference voltage	V_{REF}	0.698	0.750	0.803	V

Table 94 • HSTL DC Input Voltage Specification

Parameter	Symbol	Min	Max	Unit
DC input logic high	V_{IH} (DC)	$V_{REF} + 0.1$	1.575	V
DC input logic low	V_{IL} (DC)	-0.3	$V_{REF} - 0.1$	V
Input current high ¹	I_{IH} (DC)			
Input current low ¹	I_{IL} (DC)			

1. See Table 24, page 22.

2.3.6.6 Low Power Double Data Rate (LPDDR)

LPDDR reduced and full drive low power double data rate standards are supported in IGLOO2 FPGA and SmartFusion2 SoC FPGA I/Os. This standard requires a differential amplifier input buffer and a push-pull output buffer.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 139 • LPDDR DC Recommended DC Operating Conditions

Parameter	Symbol	Min	Typ	Max
Supply voltage	V_{DDI}	1.71	1.8	1.89
Termination voltage	V_{TT}	0.838	0.900	0.964
Input reference voltage	V_{REF}	0.838	0.900	0.964

Table 140 • LPDDR DC Input Voltage Specification

Parameter	Symbol	Min	Max
DC input logic high	V_{IH} (DC)	$0.7 \times V_{DDI}$	1.89
DC input logic low	V_{IL} (DC)	-0.3	$0.3 \times V_{DDI}$
Input current high ¹	I_{IH} (DC)		
Input current low ¹	I_{IL} (DC)		

1. See Table 24, page 22.

Table 141 • LPDDR DC Output Voltage Specification Reduced Drive

Parameter	Symbol	Min	Max
DC output logic high	V_{OH}	$0.9 \times V_{DDI}$	
DC output logic low	V_{OL}		$0.1 \times V_{DDI}$
Output minimum source DC current	I_{OH} at V_{OH}	0.1	
Output minimum sink current	I_{OL} at V_{OL}		-0.1

Table 142 • LPDDR DC Output Voltage Specification Full Drive¹

Parameter	Symbol	Min	Max
DC output logic high	V_{OH}	$0.9 \times V_{DDI}$	
DC output logic low	V_{OL}		$0.1 \times V_{DDI}$
Output minimum source DC current	I_{OH} at V_{OH}	0.1	
Output minimum sink current	I_{OL} at V_{OL}		-0.1

1. To meet JEDEC Electrical Compliance, use LPDDR Full Drive Transmitter.

Table 143 • LPDDR DC Differential Voltage Specification

Parameter	Symbol	Min
DC input differential voltage	V_{ID} (DC)	$0.4 \times V_{DDI}$

Table 159 • LPDDR-LVCMOS 1.8 V AC Switching Characteristics for Transmitter for DDRIO I/O Bank (Output and Tristate Buffers) (continued)

medium	3.246	3.819	2.686	3.16	3.236	3.807	5.542	6.52	4.936	5.807	ns	
medium_fast	3.066	3.607	2.525	2.971	3.054	3.593	5.405	6.359	4.811	5.66	ns	
fast	3.046	3.584	2.513	2.957	3.034	3.57	5.401	6.353	4.803	5.651	ns	
10 mA	slow	3.498	4.115	2.878	3.386	3.481	4.096	6.046	7.113	5.444	6.404	ns
	medium	3.138	3.692	2.569	3.023	3.126	3.678	5.782	6.803	5.129	6.034	ns
	medium_fast	2.966	3.489	2.414	2.841	2.951	3.472	5.666	6.665	5.013	5.897	ns
	fast	2.945	3.464	2.401	2.826	2.93	3.448	5.659	6.658	5.003	5.886	ns
12 mA	slow	3.417	4.02	2.807	3.303	3.401	4.002	6.083	7.156	5.464	6.428	ns
	medium	3.076	3.618	2.519	2.964	3.063	3.604	5.828	6.856	5.176	6.089	ns
	medium_fast	2.913	3.427	2.376	2.795	2.898	3.41	5.725	6.736	5.072	5.966	ns
	fast	2.894	3.405	2.362	2.78	2.879	3.388	5.715	6.724	5.064	5.957	ns
16 mA	slow	3.366	3.96	2.751	3.237	3.348	3.939	6.226	7.324	5.576	6.56	ns
	medium	3.03	3.565	2.47	2.906	3.017	3.55	5.981	7.036	5.282	6.214	ns
	medium_fast	2.87	3.377	2.328	2.739	2.854	3.358	5.895	6.935	5.18	6.094	ns
	fast	2.853	3.357	2.314	2.723	2.837	3.338	5.889	6.929	5.177	6.09	ns

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management).

2.3.7 Differential I/O Standards

Configuration of the I/O modules as a differential pair is handled by Microsemi SoC Products Group Libero software when the user instantiates a differential I/O macro in the design. Differential I/Os can also be used in conjunction with the embedded Input register (InReg), Output register (OutReg), Enable register (EnReg), and Double Data Rate registers (DDR).

2.3.7.1 LVDS

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard.

Minimum and Maximum Input and Output Levels

Table 160 • LVDS Recommended DC Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	V _{DDI}	2.375	2.5	2.625	V	2.5 V range
Supply voltage	V _{DDI}	3.15	3.3	3.45	V	3.3 V range

Table 161 • LVDS DC Input Voltage Specification

Parameter	Symbol	Min	Max	Unit	Conditions
DC Input voltage	V _I	0	2.925	V	2.5 V range
DC input voltage	V _I	0	3.45	V	3.3 V range
Input current high ¹	I _{IH} (DC)				
Input current low ¹	I _{IL} (DC)				

1. See Table 24, page 22.

Table 162 • LVDS DC Output Voltage Specification

Parameter	Symbol	Min	Typ	Max	Unit
DC output logic high	V_{OH}	1.25	1.425	1.6	V
DC output logic low	V_{OL}	0.9	1.075	1.25	V

Table 163 • LVDS DC Differential Voltage Specification

Parameter	Symbol	Min	Typ	Max	Unit
Differential output voltage swing	V_{OD}	250	350	450	mV
Output common mode voltage	V_{OCM}	1.125	1.25	1.375	V
Input common mode voltage	V_{ICM}	0.05	1.25	2.35	V
Input differential voltage	V_{ID}	100	350	600	mV

Table 164 • LVDS Minimum and Maximum AC Switching Speed

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for MSIO I/O bank)	D_{MAX}	535	Mbps	AC loading: 12 pF / 100 Ω differential load
Maximum data rate (for MSIOD I/O bank) no pre-emphasis	D_{MAX}	620	Mbps	AC loading: 10 pF / 100 Ω differential load
		700	Mbps	AC loading: 2 pF / 100 Ω differential load

Table 165 • LVDS AC Impedance Specifications

Parameter	Symbol	Typ	Max	Unit
Termination resistance	R_T	100		Ω

Table 166 • LVDS AC Test Parameter Specifications

Parameter	Symbol	Typ	Unit
Measuring/trip point for data path	V_{TRIP}	Cross point	V
Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ})	R_{ENT}	2K	Ω
Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ})	C_{ENT}	5	pF

LVDS25 AC Switching CharacteristicsWorst commercial-case conditions: $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 2.375\text{ V}$ **Table 167 • LVDS25 Receiver Characteristics for MSIO I/O Bank (Input Buffers)**

On-Die Termination (ODT)	T_{PY}		
	-1	-Std	Unit
None	2.774	3.263	ns
100	2.775	3.264	ns

2.3.7.5 RSDS

Reduced Swing Differential Signaling (RSDS) is similar to an LVDS high-speed interface using differential signaling. RSDS has a similar implementation to LVDS devices and is only intended for point-to-point applications.

Minimum and Maximum Input and Output Levels

Table 203 • RSDS Recommended DC Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{DDI}	2.375	2.5	2.625	V

Table 204 • RSDS DC Input Voltage Specification

Parameter	Symbol	Min	Max	Unit
DC input voltage	V_I	0	2.925	V

Table 205 • RSDS DC Output Voltage Specification

Parameter	Symbol	Min	Typ	Max	Unit
DC output logic high	V_{OH}	1.25	1.425	1.6	V
DC output logic low	V_{OL}	0.9	1.075	1.25	V

Table 206 • RSDS Differential Voltage Specification

Parameter	Symbol	Min	Max	Unit
Differential output voltage swing	V_{OD}	100	600	mV
Output common mode voltage	V_{OCM}	0.5	1.5	V
Input common mode voltage	V_{ICM}	0.3	1.5	V
Input differential voltage	V_{ID}	100	600	mV

Table 207 • RSDS Minimum and Maximum AC Switching Speed

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for MSIO I/O bank)	D_{MAX}	520	Mbps	AC loading: 2 pF / 100 Ω differential load
Maximum data rate (for MSIOD I/O bank)	D_{MAX}	700	Mbps	AC loading: 2 pF / 100 Ω differential load

Table 208 • RSDS AC Impedance Specifications

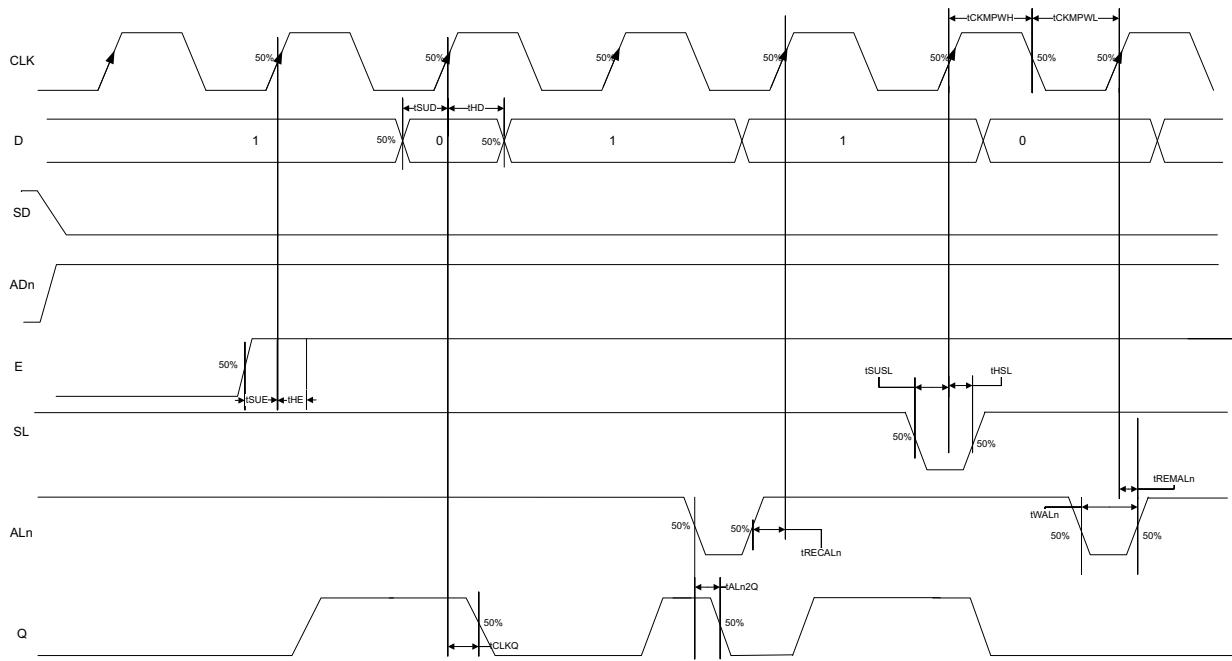
Parameter	Symbol	Typ	Unit
Termination resistance	R_T	100	Ω

Table 209 • RSDS AC Test Parameter Specifications

Parameter	Symbol	Typ	Unit
Measuring/trip point for data path	V_{TRIP}	Cross point	V
Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ})	R_{ENT}	2K	Ω
Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ})	C_{ENT}	5	pF

The following figure shows a configuration with SD = 0 (synchronous clear) and ADn = 1 (asynchronous clear) for a flip-flop (LAT = 0).

Figure 16 • Sequential Module Timing Diagram



2.3.10.3.1 Timing Characteristics

The following table lists the register delays in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 224 • Register Delays

Parameter	Symbol	-1	-Std	Unit
Clock-to-Q of the core register	T_{CLKQ}	0.108	0.127	ns
Data setup time for the core register	T_{SUD}	0.254	0.298	ns
Data hold time for the core register	T_{HD}	0	0	ns
Enable setup time for the core register	T_{SUE}	0.335	0.394	ns
Enable hold time for the core register	T_{HE}	0	0	ns
Synchronous load setup time for the core register	T_{SUSL}	0.335	0.394	ns
Synchronous load hold time for the core register	T_{HSL}	0	0	ns
Asynchronous Clear-to-Q of the core register (ADn = 1)	T_{ALN2Q}	0.473	0.556	ns
Asynchronous preset-to-Q of the core register (ADn = 0)	T_{ALN2Q}	0.451	0.531	ns
Asynchronous load removal time for the core register	T_{REMLN}	0	0	ns
Asynchronous load recovery time for the core register	T_{RECALN}	0.353	0.415	ns
Asynchronous load minimum pulse width for the core register	T_{WALN}	0.266	0.313	ns
Clock minimum pulse width high for the core register	T_{CKMPWH}	0.065	0.077	ns
Clock minimum pulse width low for the core register	T_{CKMPWL}	0.139	0.164	ns

The following table lists the 010 device global resources in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 229 • 010 Device Global Resource

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Input low delay for global clock	T_{RCKL}	0.626	0.669	0.627	0.668	ns
Input high delay for global clock	T_{RCKH}	1.112	1.182	1.308	1.393	ns
Maximum skew for global clock	T_{RCKSW}		0.07		0.085	ns

The following table lists the 005 device global resources in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 230 • 005 Device Global Resource

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Input low delay for global clock	T_{RCKL}	0.625	0.66	0.628	0.66	ns
Input high delay for global clock	T_{RCKH}	1.126	1.187	1.325	1.397	ns
Maximum skew for global clock	T_{RCKSW}		0.061		0.072	ns

2.3.12 FPGA Fabric SRAM

See *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide* for more information.

2.3.12.1 FPGA Fabric Large SRAM (LSRAM)

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 1K × 18 in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 231 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 1K × 18

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Clock period	T_{CY}	2.5		2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125		1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125		1.323		ns
Pipelined clock period	T_{PLCY}	2.5		2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125		1.323		ns
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125		1.323		ns
Read access time with pipeline register			0.334		0.393	ns
Read access time without pipeline register	T_{CLK2Q}		2.273		2.674	ns
Access time with feed-through write timing			1.529		1.799	ns
Address setup time	T_{ADDRSU}	0.441		0.519		ns
Address hold time	T_{ADDRHD}	0.274		0.322		ns
Data setup time	T_{DSU}	0.341		0.401		ns
Data hold time	T_{DHD}	0.107		0.126		ns
Block select setup time	T_{BLKSU}	0.207		0.244		ns

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 8K × 2 in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 234 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 8K × 2

Parameter	Symbol	-1		-Std	
		Min	Max	Min	Max
Clock period	T_{CY}	2.5	2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125	1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125	1.323		ns
Pipelined clock period	T_{PLCY}	2.5	2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125	1.323		ns
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125	1.323		ns
Read access time with pipeline register			0.32	0.377	ns
Read access time without pipeline register	T_{CLK2Q}		2.272	2.673	ns
Access time with feed-through write timing			1.511	1.778	ns
Address setup time	T_{ADDRSU}	0.612	0.72		ns
Address hold time	T_{ADDRHD}	0.274	0.322		ns
Data setup time	T_{DSU}	0.33	0.388		ns
Data hold time	T_{DHD}	0.082	0.096		ns
Block select setup time	T_{BLKSU}	0.207	0.244		ns
Block select hold time	T_{BLKHD}	0.216	0.254		ns
Block select to out disable time (when pipelined register is disabled)	T_{BLK2Q}		1.511	1.778	ns
Block select minimum pulse width	T_{BLKMPW}	0.186	0.219		ns
Read enable setup time	T_{RDESU}	0.529	0.622		ns
Read enable hold time	T_{RDEHD}	0.071	0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLESU}$	0.248	0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLEHD}$	0.102	0.12		ns
Asynchronous reset to output propagation delay	T_{R2Q}		1.528	1.797	ns
Asynchronous reset removal time	T_{RSTREM}	0.506	0.595		ns
Asynchronous reset recovery time	T_{RSTREC}	0.004	0.005		ns
Asynchronous reset minimum pulse width	T_{RSTMPW}	0.301	0.354		ns
Pipelined register asynchronous reset removal time	$T_{PLRSTREM}$	-0.279	-0.328		ns
Pipelined register asynchronous reset recovery time	$T_{PLRSTREC}$	0.327	0.385		ns
Pipelined register asynchronous reset minimum pulse width	$T_{PLRSTMPW}$	0.282	0.332		ns
Synchronous reset setup time	T_{SRSTSU}	0.226	0.265		ns
Synchronous reset hold time	T_{SRSTHD}	0.036	0.043		ns
Write enable setup time	T_{WESU}	0.488	0.574		ns
Write enable hold time	T_{WEHD}	0.048	0.057		ns
Maximum frequency	F_{MAX}		400	340	MHz

The following table lists the µSRAM in 256×4 mode in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 241 • µSRAM (RAM256x4) in 256×4 Mode

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Read clock period	T_{CY}	4	4			ns
Read clock minimum pulse width high	$T_{CLKMPWH}$	1.8	1.8			ns
Read clock minimum pulse width low	$T_{CLKMPWL}$	1.8	1.8			ns
Read pipeline clock period	T_{PLCY}	4	4			ns
Read pipeline clock minimum pulse width high	$T_{PLCLKMPWH}$	1.8	1.8			ns
Read pipeline clock minimum pulse width low	$T_{PLCLKMPWL}$	1.8	1.8			ns
Read access time with pipeline register	T_{CLK2Q}		0.27		0.31	ns
Read access time without pipeline register			1.75		2.06	ns
Read address setup time in synchronous mode	T_{ADDRSU}	0.301	0.354			ns
Read address setup time in asynchronous mode		1.931	2.272			ns
Read address hold time in synchronous mode	T_{ADDRHD}	0.121	0.142			ns
Read address hold time in asynchronous mode		-0.65	-0.76			ns
Read enable setup time	T_{RDENSU}	0.278	0.327			ns
Read enable hold time	T_{RDENHD}	0.057	0.067			ns
Read block select setup time	T_{BLKSU}	1.839	2.163			ns
Read block select hold time	T_{BLKHD}	-0.65	-0.77			ns
Read block select to out disable time (when pipelined register is disabled)	T_{BLK2Q}		2.09		2.46	ns
Read asynchronous reset removal time (pipelined clock)	T_{RSTREM}	-0.02	-0.03			ns
Read asynchronous reset removal time (non-pipelined clock)		0.046	0.054			ns
Read asynchronous reset recovery time (pipelined clock)	T_{RSTREC}	0.507	0.597			ns
Read asynchronous reset recovery time (non-pipelined clock)		0.236	0.278			ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	T_{R2Q}		0.83		0.98	ns
Read synchronous reset setup time	T_{SRSTSU}	0.271	0.319			ns
Read synchronous reset hold time	T_{SRSTHD}	0.061	0.071			ns
Write clock period	T_{CCY}	4	4			ns
Write clock minimum pulse width high	$T_{CCLKMPWH}$	1.8	1.8			ns
Write clock minimum pulse width low	$T_{CCLKMPWL}$	1.8	1.8			ns
Write block setup time	T_{BLKCSU}	0.404	0.476			ns
Write block hold time	T_{BLKCHD}	0.007	0.008			ns
Write input data setup time	T_{DINCSU}	0.101	0.118			ns
Write input data hold time	T_{DINCHD}	0.137	0.161			ns
Write address setup time	$T_{ADDRCSU}$	0.088	0.104			ns

Table 241 • μSRAM (RAM256x4) in 256 × 4 Mode (continued)

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Write address hold time	T _{ADDRHD}	0.245		0.288		ns
Write enable setup time	T _{WECSU}	0.397		0.467		ns
Write enable hold time	T _{WECHD}	-0.03		-0.03		ns
Maximum frequency	F _{MAX}			250	250	MHz

The following table lists the μSRAM in 512 × 2 mode in worst commercial-case conditions when T_J = 85 °C, V_{DD} = 1.14 V.

Table 242 • μSRAM (RAM512x2) in 512 × 2 Mode

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Read clock period	T _{CY}	4		4		ns
Read clock minimum pulse width high	T _{CLKMPWH}	1.8		1.8		ns
Read clock minimum pulse width low	T _{CLKMPWL}	1.8		1.8		ns
Read pipeline clock period	T _{PLCY}	4		4		ns
Read pipeline clock minimum pulse width high	T _{PLCLKMPWH}	1.8		1.8		ns
Read pipeline clock minimum pulse width low	T _{PLCLKMPWL}	1.8		1.8		ns
Read access time with pipeline register	T _{CLK2Q}		0.27		0.31	ns
Read access time without pipeline register			1.76		2.08	ns
Read address setup time in synchronous mode	T _{ADDRSU}	0.301		0.354		ns
Read address setup time in asynchronous mode		1.96		2.306		ns
Read address hold time in synchronous mode	T _{ADDRHD}	0.137		0.161		ns
Read address hold time in asynchronous mode		-0.58		-0.68		ns
Read enable setup time	T _{RDENSU}	0.278		0.327		ns
Read enable hold time	T _{RDENHD}	0.057		0.067		ns
Read block select setup time	T _{BLKSU}	1.839		2.163		ns
Read block select hold time	T _{BLKHD}	-0.65		-0.77		ns
Read block select to out disable time (when pipelined register is disabled)	T _{BLK2Q}		2.14		2.52	ns
Read asynchronous reset removal time (pipelined clock)		-0.02		-0.03		ns
Read asynchronous reset removal time (non-pipelined clock)	T _{RSTREM}	0.046		0.054		ns
Read asynchronous reset recovery time (pipelined clock)		0.507		0.597		ns
Read asynchronous reset recovery time (non-pipelined clock)	T _{RSTREC}	0.236		0.278		ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	T _{R2Q}		0.83		0.98	ns
Read synchronous reset setup time	T _{SRSTSU}	0.271		0.319		ns
Read synchronous reset hold time	T _{SRSTHD}	0.061		0.071		ns

Table 248 • 2 Step IAP Programming (eNVM Only)

M2S/M2GL	Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	2	37	5	Sec	
010	274816	4	76	11	Sec	
025	274816	4	78	10	Sec	
050	278528	3	85	9	Sec	
060	268480	5	76	22	Sec	
090	544496	10	152	43	Sec	
150	544496	10	153	44	Sec	

Table 249 • 2 Step IAP Programming (Fabric and eNVM)

M2S/M2GL	Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	6	56	11	Sec	
010	842688	11	100	21	Sec	
025	1497408	19	113	32	Sec	
050	2695168	32	136	48	Sec	
060	2686464	43	137	70	Sec	
090	4190208	68	236	115	Sec	
150	6682768	109	286	162	Sec	

Table 250 • SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)

M2S/M2GL	Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	6	19	8	Sec	
010	568784	10	26	14	Sec	
025	1223504	21	39	29	Sec	
050	2424832	39	60	50	Sec	
060	2418896	44	65	54	Sec	
090	3645968	66	90	79	Sec	
150	6139184	108	140	128	Sec	

Table 251 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)

M2S/M2GL	Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	3	42	4	Sec	
010	274816	4	82	7	Sec	
025	274816	4	82	8	Sec	
050	278528	4	80	8	Sec	
060	268480	6	80	8	Sec	
090	544496	10	157	15	Sec	

Table 251 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only) (continued)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
150	544496	10	158	15	Sec

Table 252 • SmartFusion2 Cortex-M3 ISP Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	9	61	11	Sec
010	842688	15	107	21	Sec
025	1497408	26	121	35	Sec
050	2695168	43	141	55	Sec
060	2686464	48	143	60	Sec
090	4190208	75	244	91	Sec
150	6682768	117	296	141	Sec

Table 253 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric Only)

M2S/M2GL Device	Auto Programming		Programming Recovery		Unit
	100 kHz	25 MHz	12.5 MHz		
005	47	27	28		Sec
010	77	35	35		Sec
025	150	42	41		Sec
050	33 ¹	Not Supported	Not Supported		Sec
060	291	83	82		Sec
090	427	109	108		Sec
150	708	157	160		Sec

1. Auto Programming in 050 device is done through SC_SPI, and SPI CLK is set to 6.25 MHz.

Table 254 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (eNVM Only)

M2S/M2GL Device	Auto Programming		Programming Recovery		Unit
	100 kHz	25 MHz	12.5 MHz		
005	41	48	49		Sec
010	86	87	87		Sec
025	87	85	86		Sec
050	85	Not Supported	Not Supported		Sec
060	78	86	86		Sec
090	154	162	162		Sec

Table 254 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (eNVM Only) (continued)

M2S/M2GL Device	Auto Programming	Auto Update	Programming Recovery	Unit
	100 kHz	25 MHz	12.5 MHz	
150	161	161	161	Sec

Table 255 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric and eNVM)

M2S/M2GL Device	Auto Programming	Auto Update	Programming Recovery	Unit
	100 kHz	25 MHz	12.5 MHz	
005	47	27	28	Sec
010	77	35	35	Sec
025	150	42	41	Sec
050	33 ¹	Not Supported	Not Supported	Sec
060	291	83	82	Sec
090	427	109	108	Sec
150	708	157	160	Sec
005	41	48	49	Sec
010	86	87	87	Sec
025	87	85	86	Sec
050	85	Not Supported	Not Supported	Sec
060	78	86	86	Sec
090	154	162	162	Sec
150	161	161	161	Sec
005	87	67	66	Sec
010	161	113	113	Sec
025	229	120	121	Sec
050	112	Not Supported	Not Supported	Sec
060	368	161	158	Sec
090	582	261	260	Sec
150	867	309	310	Sec

1. Auto Programming in 050 device is done through SC_SPI, and SPI CLK is set to 6.25 MHz.

Table 262 • SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	6	41	8	Sec
010	568784	10	48	14	Sec
025	1223504	21	61	29	Sec
050	2424832	39	82	50	Sec
060	2418896	44	87	54	Sec
090	3645968	66	112	79	Sec
150	6139184	108	162	128	Sec

Table 263 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	137536	3	64	4	Sec
010	274816	4	104	7	Sec
025	274816	4	104	8	Sec
050	2,78,528	4	102	8	Sec
060	268480	6	102	8	Sec
090	544496	10	179	15	Sec
150	544496	10	180	15	Sec

Table 264 • SmartFusion2 Cortex-M3 ISP Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	439296	9	83	11	Sec
010	842688	15	129	21	Sec
025	1497408	26	143	35	Sec
050	2695168	43	163	55	Sec
060	2686464	48	165	60	Sec
090	4190208	75	266	91	Sec
150	6682768	117	318	141	Sec

2.3.20 On-Chip Oscillator

The following tables describe the electrical characteristics of the available on-chip oscillators in the IGLOO2 FPGAs and SmartFusion2 SoC FPGAs.

Table 280 • Electrical Characteristics of the 50 MHz RC Oscillator

Parameter	Symbol	Typ	Max	Unit	Condition
Operating frequency	F50RC	50		MHz	
Accuracy	ACC50RC	1	4	%	050 devices
		1	5	%	005, 025, and 060 devices
		1	6.3	%	090 devices
		1	7.1	%	010 and 150 devices
Output duty cycle	CYC50RC	49–51	46.5–53.5	%	
Output jitter (peak to peak)	JIT50RC				Period Jitter
		200	300	ps	005, 010, 050, and 060 devices
		200	400	ps	150 devices
		300	500	ps	025 and 090 devices
					Cycle-to-Cycle Jitter
		200	300	ps	005 and 050 devices
		320	420	ps	010, 060, and 150 devices
		320	850	ps	025 and 090 devices
Operating current	IDYN50RC	6.5		mA	

Table 281 • Electrical Characteristics of the 1 MHz RC Oscillator

Parameter	Symbol	Typ	Max	Unit	Condition
Operating frequency	F1RC	1		MHz	
Accuracy	ACC1RC	1	3	%	005, 010, 025, and 050 devices
		1	4.5	%	060, and 150 devices
		1	5.6	%	090 devices
Output duty cycle	CYC1RC	49–51	46.5–53.5	%	005, 010, 025, 050, 090 and 150 devices
		49–51	46.0–54.0	%	060 devices
Output jitter (peak to peak)	JIT1RC				Period Jitter
		10	20	ns	005, 010, 025, and 050 devices
		10	28	ns	060, 090 and 150 devices
					Cycle-to-Cycle Jitter
		10	20	ns	005, 010, and 050 devices
		10	35	ns	025, 060, and 150 devices
		10	45	ns	090 devices
Operating current	IDYN1RC	0.1		mA	
Startup time	SU1RC	17	μ s		050, 090, and 150 devices
		18	μ s		005, 010, and 025 devices

2.3.24 Power-up to Functional Times

The following table lists the SmartFusion2 power-up to functional times in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

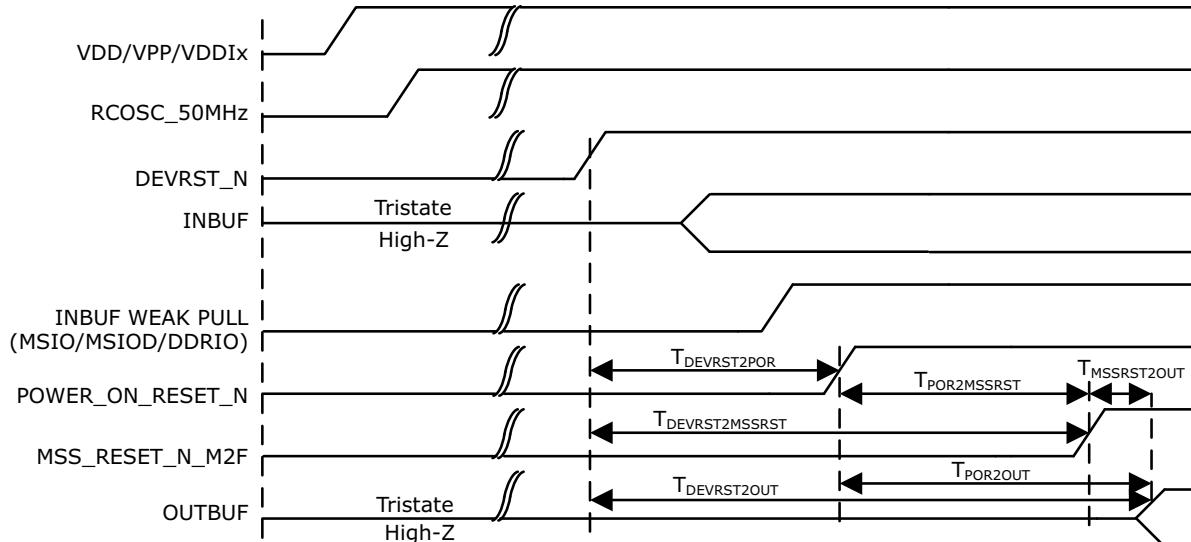
Table 288 • Power-up to Functional Times for SmartFusion2

Symbol	From	To	Description	Maximum Power-up to Functional Time for SmartFusion2 (uS)						
				005	010	025	050	060	090	150
$T_{POR2OUT}$	POWER_ON _RESET_N	Output available at I/O	Fabric to output	647	500	531	483	474	524	647
$T_{POR2MSSRST}$	POWER_ON _RESET_N	MSS_RESET_T_N_M2F	Fabric to MSS	644	497	528	480	468	518	641
$T_{MSSRST2OUT}$	MSS_RESET_N_M2F	Output available at I/O	MSS to output	3.6	3.6	3.6	3.4	4.9	4.8	4.8
$T_{VDD2OUT}$	V_{DD}	Output available at I/O	V_{DD} at its minimum threshold level to output	3096	2975	3012	2959	2869	2992	3225
$T_{VDD2POR}$	V_{DD}	POWER_ON_RESET_N	V_{DD} at its minimum threshold level to fabric	2476	2487	2496	2486	2406	2563	2602
$T_{VDD2MSSRST}$	V_{DD}	MSS_RESET_T_N_M2F	V_{DD} at its minimum threshold level to MSS	3093	2972	3008	2956	2864	2987	3220
$T_{VDD2WPU}$	DEVRST_N	DDRIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	2500	2487	2509	2475	2507	2519	2617
	DEVRST_N	MSIOT Inbuf weak pull	DEVRST_N to Inbuf weak pull	2504	2491	2510	2478	2517	2525	2620
	DEVRST_N	MSIOD Inbuf weak pull	DEVRST_N to Inbuf weak pull	2479	2468	2493	2458	2486	2499	2595

Note: For more information about power-up times, see *UG0331: SmartFusion2 Microcontroller Subsystem User Guide*.

Table 291 • DEVRST_N to Functional Times for SmartFusion2 (continued)

Symbol	From	To	Description	Maximum Power-up to Functional Time for SmartFusion2 (uS)						
				005	010	025	050	060	090	150
T _{DEVRST2POR}	DEVRST_N	POWER_O N_RESET_ N	V _{DD} at its minimum threshold level to fabric	233	289	216	213	237	234	219
T _{DEVRST2MSSRST}	DEVRST_N	MSS_RESET_N_M2F	V _{DD} at its minimum threshold level to MSS	702	765	712	688	636	630	866
T _{DEVRST2WPU}	DEVRST_N	DDRIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215
	DEVRST_N	MSIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215
	DEVRST_N	MSIOD Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215

Figure 19 • DEVRST_N to Functional Timing Diagram for SmartFusion2

2.3.34 MMUART Characteristics

The following table lists the MMUART characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 308 • MMUART Characteristics

Parameter	Description	-1	-Std	Unit
FMMUART_REF_CLK	Internally sourced MMUART reference clock frequency.	166	142	MHz
BAUDMMUARTTx	Maximum transmit baud rate	10.375	8.875	Mbps
BAUDMMUARTRx	Maximum receive baud rate	10.375	8.875	Mbps

2.3.35 IGLOO2 Specifications

2.3.35.1 HPMS Clock Frequency

The following table lists the maximum frequency for HPMS main clock in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 309 • Maximum Frequency for HPMS Main Clock

Symbol	Description	-1	-Std	Unit
HPMS_CLK	Maximum frequency for the HPMS main clock	166	142	MHz

2.3.35.2 IGLOO2 Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given are for a 35 pF load on the pins and all sequential timing characteristics are related to SPI_0_CLK. For timing parameter definitions, see Figure 23, page 131.

The following table lists the SPI characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 310 • SPI Characteristics for All Devices

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPIFMAX	Maximum operating frequency of SPI interface			20	MHz	
sp1	SPI_[0 1]_CLK minimum period					
	SPI_[0 1]_CLK = PCLK/2	12			ns	
	SPI_[0 1]_CLK = PCLK/4	24.1			ns	
	SPI_[0 1]_CLK = PCLK/8	48.2			ns	
	SPI_[0 1]_CLK = PCLK/16	0.1			μs	
	SPI_[0 1]_CLK = PCLK/32	0.19			μs	
	SPI_[0 1]_CLK = PCLK/64	0.39			μs	
	SPI_[0 1]_CLK = PCLK/128	0.77			μs	

Table 310 • SPI Characteristics for All Devices (continued)

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPI master configuration (applicable for 060, 090, and 150 devices)						
sp6m	SPI_[0 1]_DO setup time ²	(SPI_x_CLK_period/2) – 7.0			ns	
sp7m	SPI_[0 1]_DO hold time ²	(SPI_x_CLK_period/2) – 9.5			ns	
sp8m	SPI_[0 1]_DI setup time ²	15			ns	
sp9m	SPI_[0 1]_DI hold time ²	-2.5			ns	
SPI slave configuration (applicable for 060, 090, and 150 devices)						
sp6s	SPI_[0 1]_DO setup time ²	(SPI_x_CLK_period/2) – 16.0			ns	
sp7s	SPI_[0 1]_DO hold time ²	(SPI_x_CLK_period/2) - 3.5			ns	
sp8s	SPI_[0 1]_DI setup time ²	3			ns	
sp9s	SPI_[0 1]_DI hold time ²	2.5			ns	

1. For specific Rise/Fall Times board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>.
2. For allowable pclk configurations, see the Serial Peripheral Interface Controller section in the *UG0331: SmartFusion2 Microcontroller Subsystem User Guide*.

Figure 23 • SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1)